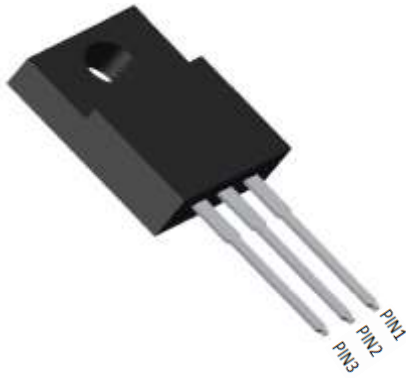




## Schottky Diodes



### Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

### Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### Mechanical Data

- **Package:** ITO-220AB  
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

### ■Maximum Ratings (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR10100FCT	MBR10150FCT	MBR10200FCT
Device marking code			MBR10100FCT	MBR10150FCT	MBR10200FCT
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	V	100	150	200
Average Rectified Output Current @60Hz sine wave, R-load, T <sub>c</sub> (FIG.1)	I <sub>o</sub>	A	10		
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T <sub>a</sub> =25°C	I <sub>FSM</sub>	A	120		
Current Squared Time @1ms≤t<8.3ms T <sub>j</sub> =25°C,	I <sup>2</sup> t	A <sup>2</sup> s	60		
Storage Temperature	T <sub>stg</sub>	°C	-55 ~ +175		
Junction Temperature	T <sub>j</sub>	°C	-55 ~ +175		

### ■Electrical Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR10100FCT	MBR10150FCT	MBR10200FCT
Maximum instantaneous forward voltage drop per diode	V <sub>FM</sub>	V	I <sub>FM</sub> =5.0A	0.8	0.85	0.9
Maximum DC reverse current at rated DC blocking voltage per diode	I <sub>R1</sub>	mA	V <sub>RM</sub> =V <sub>RRM</sub> T <sub>a</sub> =25°C	0.1		
	I <sub>R2</sub>		V <sub>RM</sub> =V <sub>RRM</sub> T <sub>a</sub> =125°C	20		

Note1:Pulse test:300uS pulse width,1% duty cycle

Note2:Pulse test:pulse width 40mS

### ■Thermal Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR10100FCT	MBR10150FCT	MBR10200FCT
Thermal Resistance Between junction and case	R <sub>θJ-C</sub>	°C/W	4.0		



# MBR10100FCT THRU MBR10200FCT

## Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR10100FCT THRU MBR10200FCT	Approximate 1.6	50	1000	5000	Tube

## Characteristics (Typical)

FIG1:  $I_o$  -  $T_c$  Curve

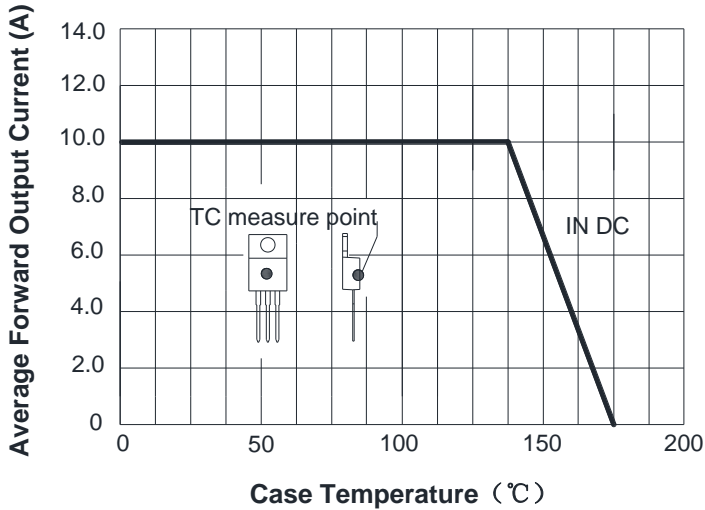


FIG2: Surge Forward Current Capability

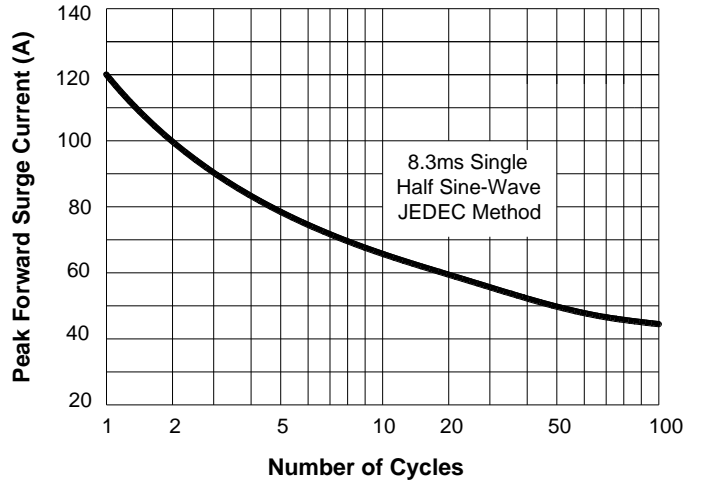


FIG3: Forward Voltage

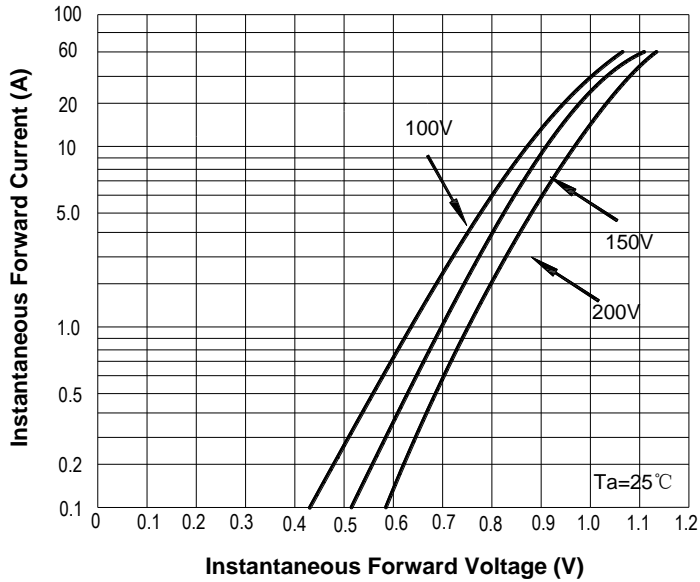
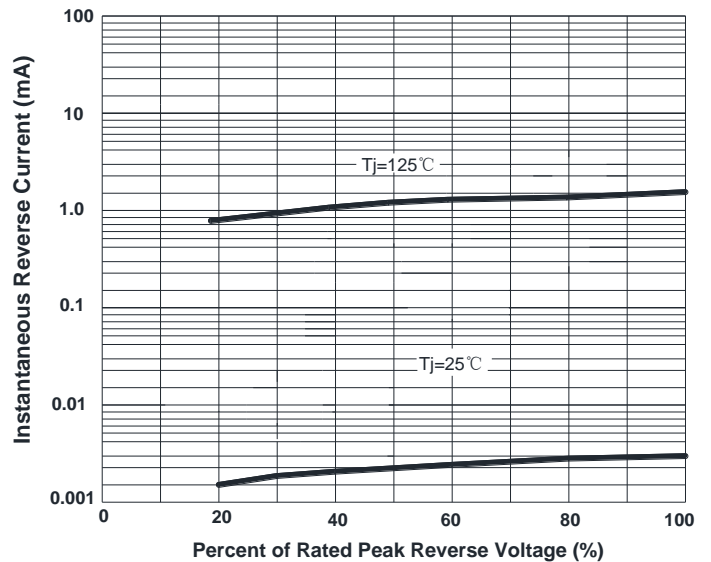


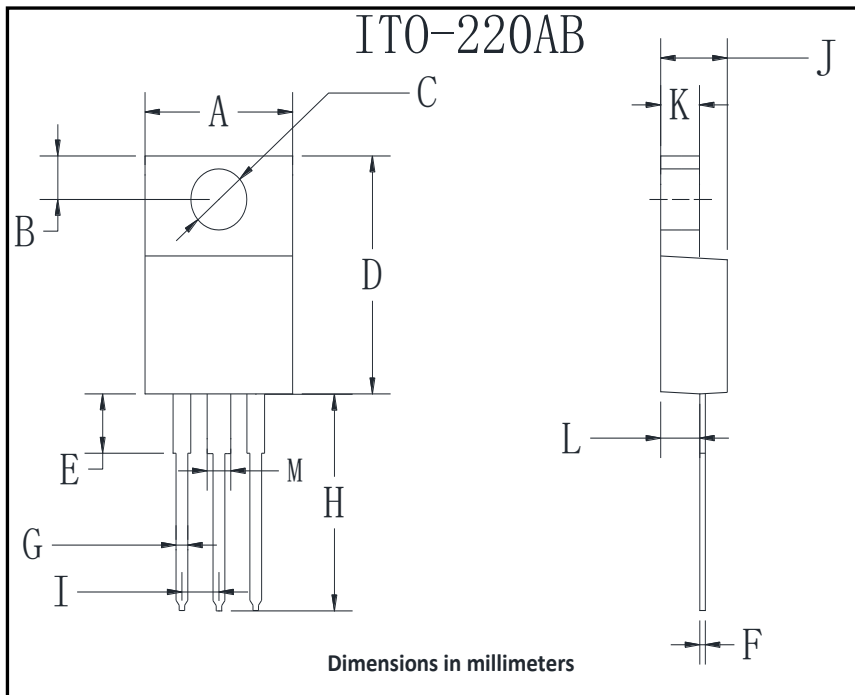
FIG4: Instantaneous Reverse Characteristics





# MBR10100FCT THRU MBR10200FCT

## ■Outline Dimensions



ITO-220AB		
Dim	Min	Max
A	9.8	10.2
B	2.25	2.75
C	2.95	3.45
D	14.75	15.25
E	3.05	3.95
F	0.45	0.75
G	0.45	0.75
H	13.4	14.2
I	2.35	2.75
J	4.3	4.8
K	2.58	2.82
L	2.58	2.82
M	1.47	1.77



## MBR10100FCT THRU MBR10200FCT

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